

**GaAlAs-IR-Lumineszenzdiode (880 nm) und grüne GaP-LED (565 nm)**  
**GaAlAs-Infrared-Emitter (880 nm) and green GaP-LED (565 nm)**  
**Lead (Pb) Free Product - RoHS Compliant**

**SFH 7222**



**Wesentliche Merkmale**

- SMT-Gehäuse mit IR-Sender (880 nm) und grünem Sender (565 nm)
- Geeignet für SMT-Bestückung
- Gegurtet lieferbar
- Sender und Empfänger getrennt ansteuerbar

**Anwendungen**

- Kombination von Anzeigeelement mit:
  - Datenübertragung
  - Fernsteuerung
  - Infrarotschnittstelle

**Features**

- SMT package with IR emitter (880 nm) and green emitter (565 nm)
- Suitable for SMT assembly
- Available on tape and reel
- Emitter und detector can be controlled separately

**Applications**

- Combination of display with:
  - data transmission
  - remote control
  - infrared interface

Typ Type	Bestellnummer Ordering Code	Gehäuse Package
SFH 7222	Q65110A2742	SMT Multi TOPLED®

**Grenzwerte**  
**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		IRED	LED	
Betriebstemperatur Operating temperature range	$T_{op}$	- 40 ... + 100	- 40 ... + 100	°C
Lagertemperatur Storage temperature range	$T_{stg}$	- 40 ... + 100	- 40 ... + 100	°C
Sperrspannung Reverse voltage	$V_R$	5	5	V
Durchlassstrom Forward current	$I_F$ (DC)	100	30	mA
Stoßstrom Surge current $t_p \leq 10 \mu s, D = 0$	$I_{FSM}$	2.5	0.5	A
Verlustleistung Total power dissipation	$P_{tot}$	180	100	mW
Wärmewiderstand Thermal resistance junction/ambient <sup>1)</sup>	$R_{th JA}$	450	500	K/W
Wärmewiderstand Thermal resistance junction/ambient <sup>2)</sup>	$R_{th JA}$	650		K/W

<sup>1)</sup> nur ein Chip betrieben / only one chip on

<sup>2)</sup> beide Chips betrieben / both chips on

**Hinweis/Notes**

Die angegebenen Grenzdaten gelten für einen Chip, wenn nicht anders angegeben.  
The stated maximum ratings refer to one chip, unless otherwise specified.

Kennwerte ( $T_A = 25\text{ °C}$ )

## Characteristics

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		IRED	LED	
Wellenlänge der Strahlung Wavelength of peak emission $I_F = 100\text{ mA}$	$\lambda_{\text{peak}}$	880	565 ( $I_F = 10\text{ mA}$ )	nm
Dominantwellenlänge Dominant wavelength $I_F = 10\text{ mA}$	$\lambda_{\text{dom}}$	–	570	nm
Spektrale Bandbreite bei 50% von $I_{\text{max}}$ Spectral bandwidth at 50% of $I_{\text{max}}$ $I_F = 100\text{ mA}$	$\Delta\lambda$	80	25 ( $I_F = 10\text{ mA}$ )	nm
Abstrahlwinkel Half angle	$\varphi$	$\pm 60$	$\pm 60$	Grad deg.
Abmessungen der aktiven Chipfläche Dimensions of the active chip area	$L \times B$ $L \times W$	$0.4 \times 0.4$	$0.25 \times 0.25$	$\text{mm}^2$
Schaltzeiten Switching times 10%/90%, $I_F = 100\text{ mA}$ , $R_L = 50\ \Omega$	$t_r, t_f$	500	450, 200	ns
Kapazität Capacitance $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$	$C_o$	25	15	pF
Durchlassspannung Forward voltage $I_F = 10\text{ mA}$ $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$ $I_F = 1\text{ A}$ , $t_p = 100\ \mu\text{s}$	$V_F$	– 1.5 ( $\leq 1.8$ ) 3.0 ( $\leq 3.8$ )	2.0 ( $\leq 2.6$ ) – –	V
Sperrstrom, $V_R = 5\text{ V}$ Reverse current	$I_R$	0.01 ( $\leq 1$ )	0.01 ( $\leq 10$ )	$\mu\text{A}$
Gesamtstrahlungsfluss Total radiant flux $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$	$\Phi_e$	23	–	mW
Lichtstärke Luminous intensity $I_F = 2\text{ mA}$	$I_V$	–	>0.25	mcd
Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ Temperature coefficient of $I_e$ or $\Phi_e$ $I_F = 100\text{ mA}$	$TC_1$	–0.5	–0.3	%/K

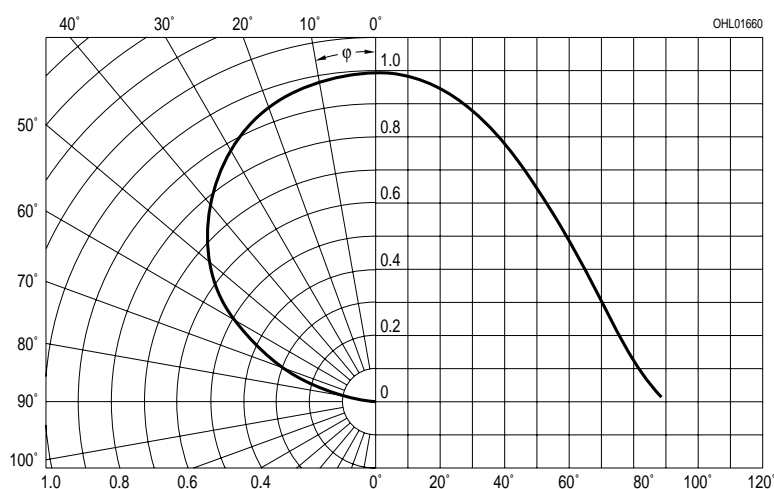
Kennwerte ( $T_A = 25\text{ °C}$ )

Characteristics (cont'd)

Bezeichnung Parameter	Symbol Symbol	Wert Value		Einheit Unit
		IRED	LED	
Temperaturkoeffizient von $V_F$ Temperature coefficient of $V_F$ $I_F = 100\text{ mA}$	$TC_V$	- 2	- 1.4	mV/K
Temperaturkoeffizient von $\lambda$ Temperature coefficient of $\lambda$ $I_F = 100\text{ mA}$	$TC_\lambda$	+ 0.25	0.30 ( $\lambda_{\text{peak}}$ ) 0.07 ( $\lambda_{\text{dom}}$ )	nm/K

Strahlstärke  $I_e$  der IRED in Achsrichtunggemessen bei einem Raumwinkel  $\Omega = 0.01\text{ sr}$ Radiant Intensity  $I_e$  of the IRED in Axial Directionat a solid angle of  $\Omega = 0.01\text{ sr}$ 

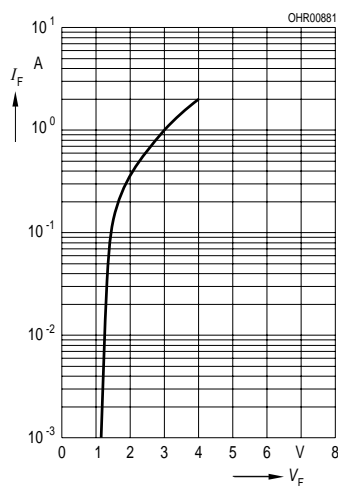
Bezeichnung Description	Symbol Symbol	Werte Values	Einheit Unit
Strahlstärke Radiant intensity $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$	$I_{e\text{ min.}}$	$\geq 4$	mW/sr
Strahlstärke Radiant intensity $I_F = 1\text{ A}$ , $t_p = 100\text{ }\mu\text{s}$	$I_{e\text{ typ.}}$	48	mW/sr

IRED Radiation Characteristics  $I_{\text{rel}} = f(\varphi)$ LED Directional Characteristics  $S_{\text{rel}} = f(\varphi)$ 

**URED**

**Forward Current**  $I_F = f(V_F)$

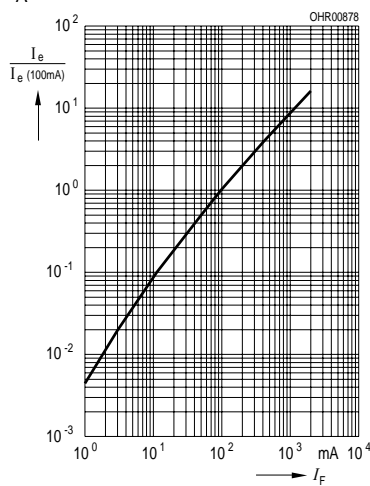
$T_A = 25\text{ }^\circ\text{C}$



**Rel Luminous Intensity**

$I_V / I_{V(10\text{ mA})} = f(I_F)$

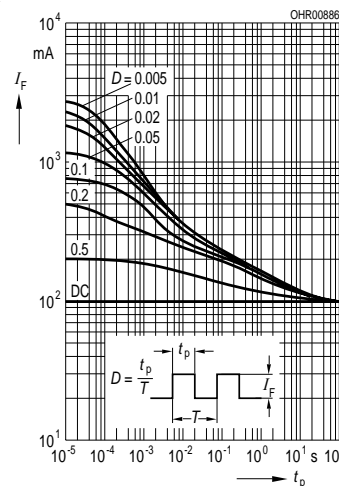
$T_A = 25\text{ }^\circ\text{C}$



**Perm. Pulse Handling Capability**

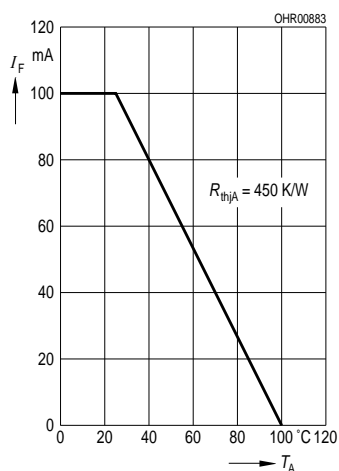
$I_F = f(t_p)$ , Duty cycle  $D = \text{parameter}$ ,

$T_A = 25\text{ }^\circ\text{C}$



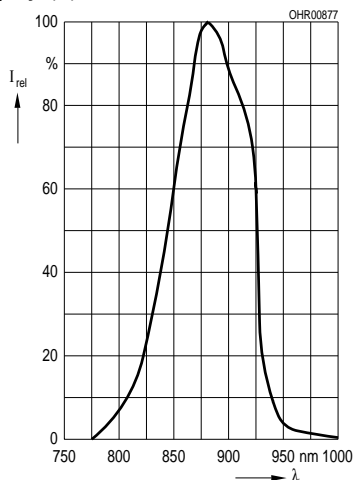
**Max. Permissible Forward Current**

$I_F = f(T_A)$



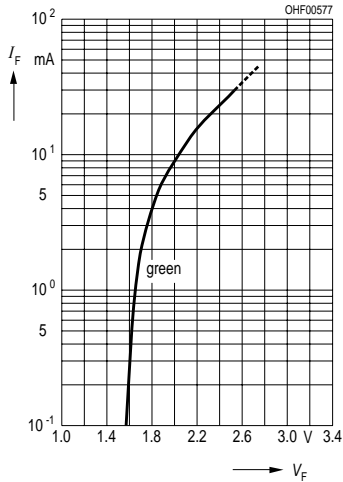
**Relative Spectral Emission**

$I_{rel} = f(\lambda)$

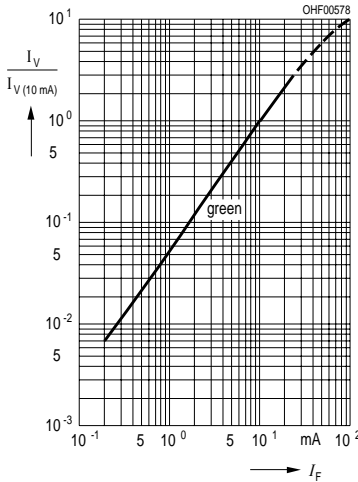


**LED**

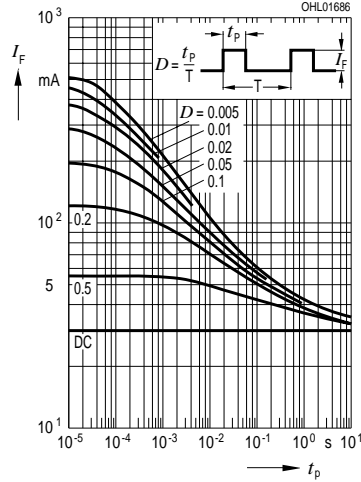
**Forward Current  $I_F = f(V_F)$**   
 $T_A = 25^\circ\text{C}$



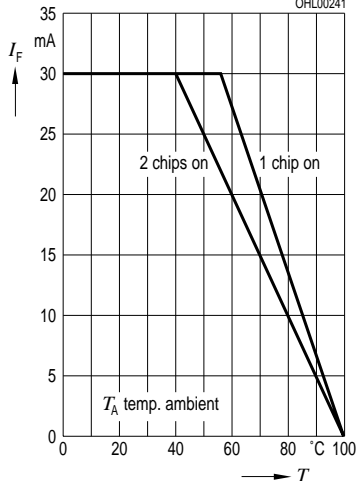
**Relative Luminous Intensity  $I_V / I_{V(10\text{ mA})} = f(I_F), T_A = 25^\circ\text{C}$**



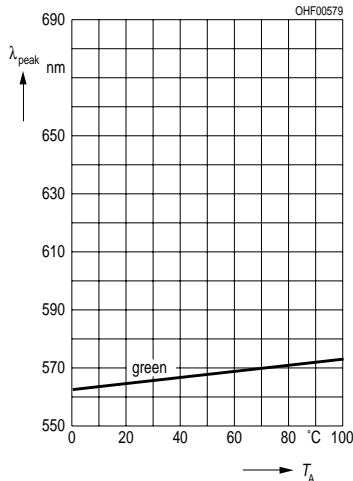
**Perm. Pulse Handling Capability  $I_F = f(t_p)$**   
 Duty cycle  $D =$  parameter,  $T_A = 25^\circ\text{C}$



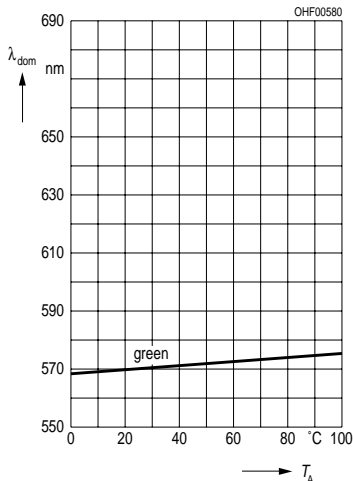
**Max. Permissible Forward Current  $I_F = f(T_A)$**



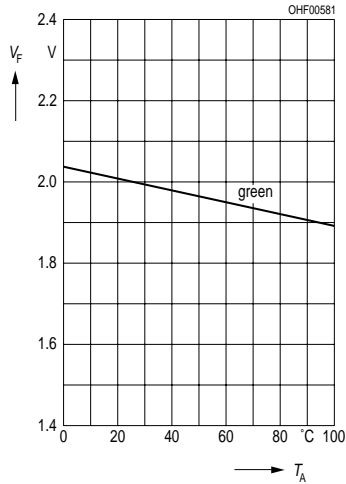
**Wavelength at Peak Emission  $\lambda_{\text{peak}} = f(T_A), I_F = 10\text{ mA}$**



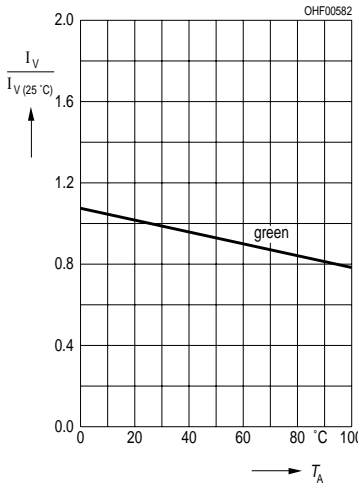
**Dominant Wavelength  $\lambda_{\text{dom}} = f(T_A), I_F = 10\text{ mA}$**



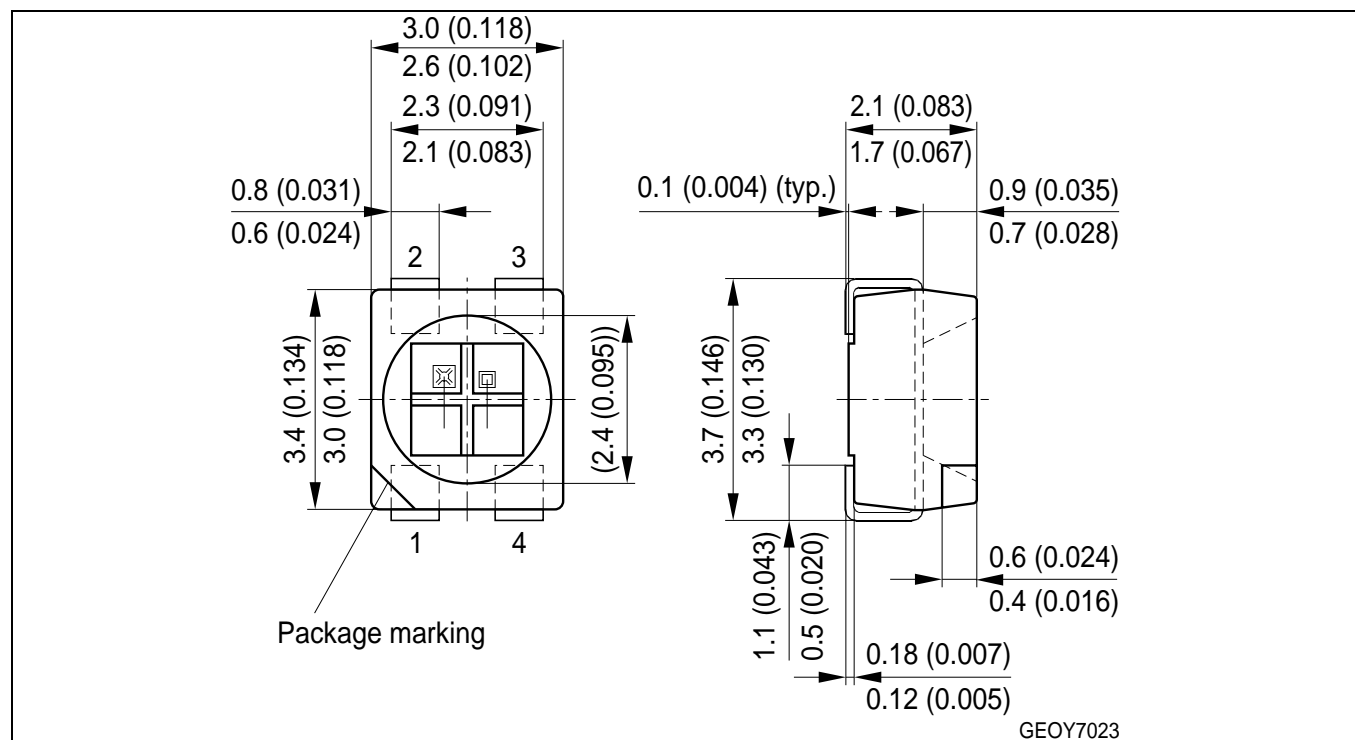
**Forward Voltage  $V_F = f(T_A)$**   
 $I_F = f(T_A)$



**Relative Luminous Intensity  $I_V / I_{V(25^\circ\text{C})} = f(I_F), I_F = 10\text{ mA}$**



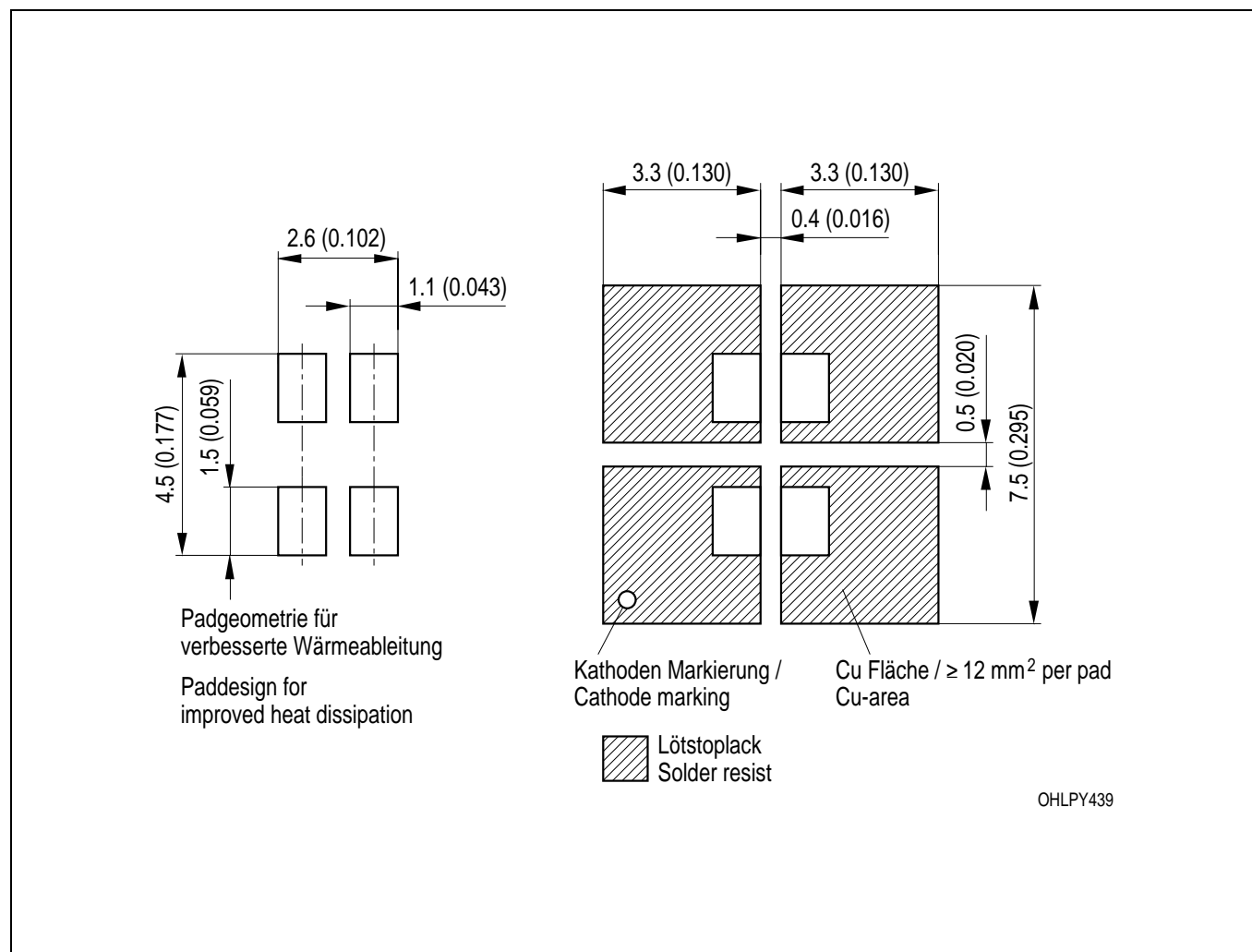
## Maßzeichnung Package Outlines



Maße in mm (inch) / Dimensions in mm (inch).

Gehäuse / Package	weiß, klarer Verguss / white, clear resin
Anschlussbelegung pin configuration	1: Kathode (cathode) 880nm 2: Anode (anode) 880nm 3: Kathode (cathode) 565nm 4: Anode (anode) 565nm

## Empfohlenes Lötpaddesign Recommended Solder Pad

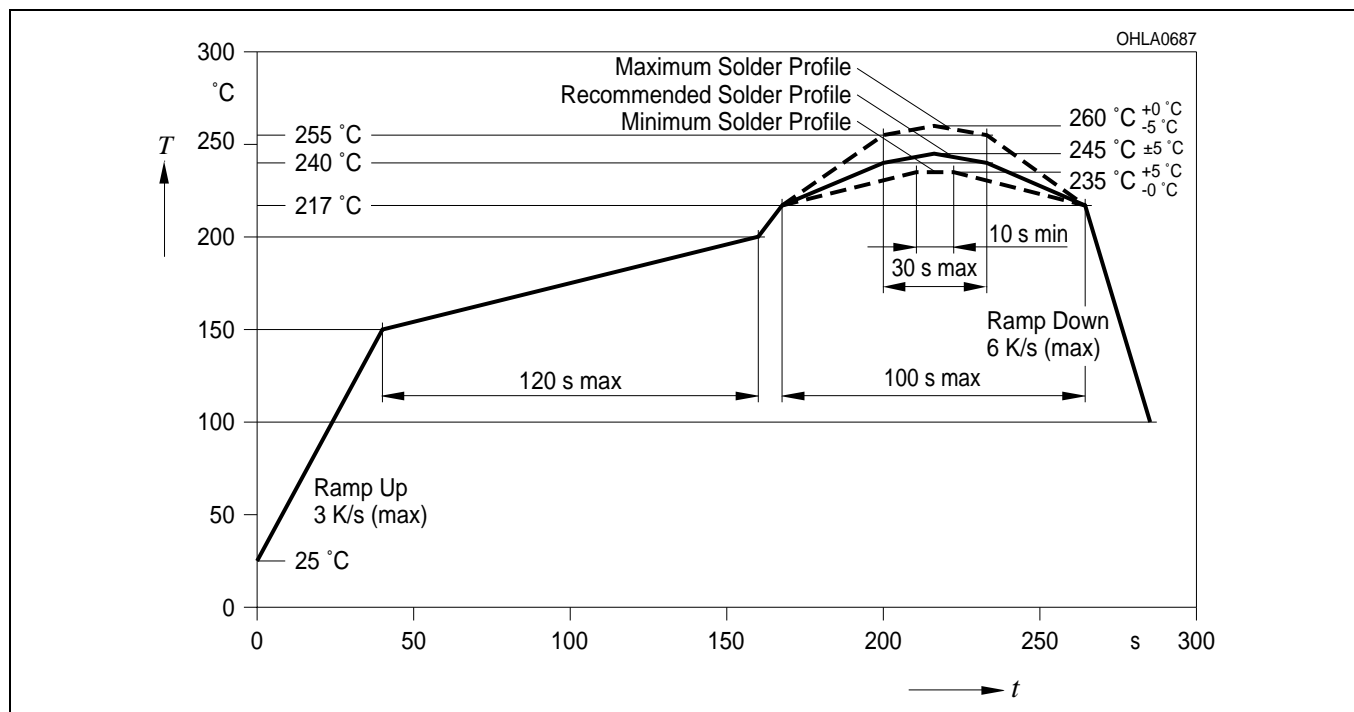


Maße in mm (inch) / Dimensions in mm (inch).



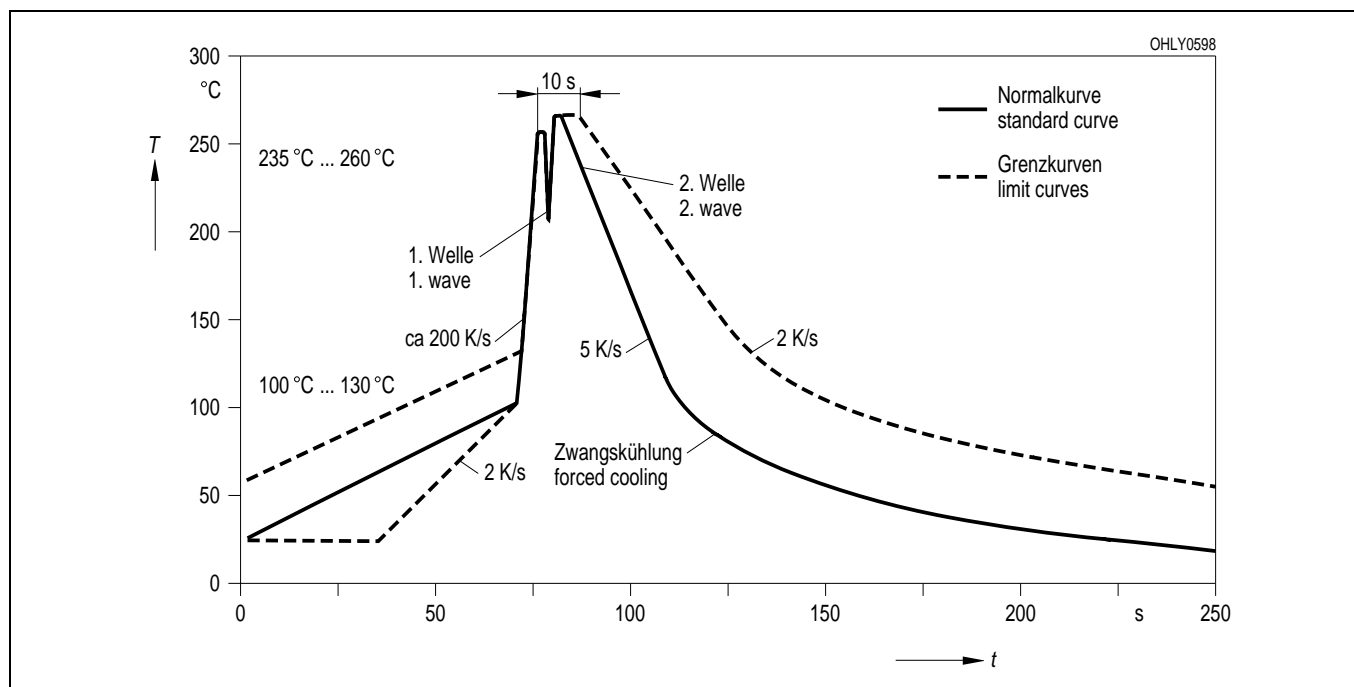
**Lötbedingungen**  
**Soldering Conditions**  
**Reflow Lötprofil für bleifreies Löt**  
**Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 2  
 Preconditioning acc. to JEDEC Level 2  
 (nach J-STD-020C)  
 (acc. to J-STD-020C)



**Wellenlöt (TTW)**  
**TTW Soldering**

(nach CECC 00802)  
 (acc. to CECC 00802)



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